

Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

Claim 1. (Currently Amended) A method, comprising:
exposing an alignment material to an interference pattern having uniform intensity formed from two beams having circular polarization states of opposite handedness to cause a chemical reaction in the alignment material; and
exposing the alignment material to a liquid crystal,
wherein the liquid crystal aligns relative to the alignment material based on the interference pattern.

Claim 2. (Original) The method of claim 1, wherein the chemical reaction causes polymerization in the alignment material.

Claim 3. (Withdrawn) The method of claim 1, wherein the chemical reaction causes depolymerization in the alignment material.

Claim 4. (Original) The method of claim 1, wherein the chemical reaction comprises a photochemical reaction.

Claim 5. (Original) The method of claim 1, wherein a surface of the alignment material is exposed to the interference pattern.

Claim 6. (Withdrawn) The method of claim 5, wherein the surface is substantially planar.

Claim 7. (Withdrawn) The method of claim 5, wherein the surface is curved.

Claim 8. (Withdrawn) The method of claim 7, wherein the surface is an inner-surface of a tube.

Claim 9. (Withdrawn) The method of claim 8, wherein the tube comprises one of a glass and a polymer.

Claim 10. (Original) The method of claim 5, wherein the surface comprises a channel.

Claim 11. (Original) The method of claim 1, wherein the alignment material is disposed on a surface of a substrate comprising a substrate material.

Claim 12. (Original) The method of claim 11, wherein the substrate material is at least one of a glass, a polymer, a metal and a semi-conductor.

Claim 13. (Original) The method of claim 12, wherein the substrate comprises an electrode layer.

Claim 14. (Original) The method of claim 13, wherein the electrode layer comprises a transparent electrically conductive material.

Claim 15. (Original) The method of claim 12, wherein the substrate comprises a thin film transistor.

Claim 16. (Original) The method of claim 1, wherein the liquid crystal permeates the alignment material.

Claim 17. (Original) The method of claim 1, wherein the alignment material comprises a liquid crystal.

Claim 18. (Original) The method of claim 1, wherein the alignment material comprises a polymer.

Claim 19. (Original) The method of claim 18, wherein the polymer comprises a cinnamate group.

Claim 20. (Original) The method of claim 18, wherein the polymer is a polyimide.

Claim 21. (Original) The method of claim 1, wherein the alignment material comprises a silane.

Claim 22. (Original) The method of claim 1, wherein the interference pattern is formed from two or more optical beams which originate from the same source.

Claim 23. (Original) The method of claim 22, wherein the optical beams comprise UV radiation.

Claim 24. (Original) The method of claim 1, wherein the interference pattern is formed from two or more electron beams.

Claims 25 - 26. (Canceled)

Claim 27. (Withdrawn) The method of claim 26, wherein the liquid crystal aligns substantially homeotropically where the alignment material is exposed to regions of high intensity.

Claim 28. (Withdrawn) The method of claim 26, wherein the liquid crystal aligns substantially homogeneously where the alignment material is exposed to regions of low intensity.

Claim 29. (Withdrawn) The method of claim 26, wherein the liquid crystal aligns substantially homeotropically where the alignment material is exposed to regions of low intensity.

Claim 30. (Withdrawn) The method of claim 26, wherein the liquid crystal aligns substantially homogeneously where the alignment material is exposed to regions of high intensity.

Claim 31. (Original) The method of claim 1, wherein the interference pattern comprises regions of different polarization.

Claim 32. (Withdrawn) The method of claim 31, wherein the interference pattern comprises regions of different linear polarization.

Claim 33. (Withdrawn) The method of claim 31, wherein the interference pattern comprises regions of linear polarization and regions of elliptical polarization.

Claim 34. (Original) The method of claim 31, wherein the liquid crystal aligns relative to the alignment material based on the polarization of the interference pattern.

Claim 35. (Withdrawn) The method of claim 1, wherein at least a portion of the liquid crystal aligns substantially homeotropically relative to a surface of the alignment material.

Claim 36. (Withdrawn) The method of claim 1, wherein at least a portion of the liquid crystal aligns obliquely relative to a surface of the alignment material.

Claim 37. (Withdrawn) The method of claim 1, wherein at least a portion of the liquid crystal aligns substantially homogeneously relative to a surface of the alignment material.

Claim 38. (Original) The method of claim 1, wherein the interference pattern is formed by overlapping two or more beams.

Claim 39. (Withdrawn) The method of claim 38, wherein two of the beams have similar polarization states.

Claim 40. (Withdrawn) The method of claim 38, wherein two of the beams have different polarization states.

Claim 41. (Original) The method of claim 38, wherein the interference pattern is formed by overlapping three or more beams and at least two of the beams have similar polarization states.

Claim 42. (Withdrawn) The method of claim 1, wherein the liquid crystal is disposed on the surface prior to exposure to the interference pattern.

Claim 43. (Withdrawn) The method of claim 1, wherein the liquid crystal is disposed on the surface after exposure to the interference pattern.

Claim 44. (Withdrawn) The method of claim 1, further comprising rubbing a surface of the alignment material prior to exposing the alignment material to the interference pattern.

Claim 45. (Withdrawn) The method of claim 1, further comprising exposing a surface of the alignment material to polarized radiation prior to exposing the alignment material to the interference pattern.

Claim 46. (Withdrawn) A method, comprising:
 exposing an alignment material to radiation; and
 exposing the alignment material to a liquid crystal,
 wherein different portions of the alignment material are simultaneously exposed to different polarization states of the radiation and the liquid crystal aligns relative to the alignment material based on the polarization state of the radiation.

Claim 47. (Withdrawn) The method of claim 46, wherein the polarization state of the radiation varies continuously across the alignment material.

Claim 48. (Withdrawn) The method of claim 46, wherein the radiation causes isomerization in the alignment material.

Claim 49. (Withdrawn) A method, comprising:
 exposing an alignment material to polarized radiation; and
 exposing the alignment material to a liquid crystal,
 wherein the polarization state of the radiation varies continuously across a portion of the alignment material and the liquid crystal aligns relative to the alignment material based on the polarization state of the radiation.

Claim 50. (Withdrawn) A method, comprising:
 exposing a curved surface comprising an alignment material to polarized radiation; and

disposing a liquid crystal on the curved surface;
wherein the liquid crystal aligns substantially parallel to an alignment direction related to the polarized radiation.

Claim 51. (Withdrawn) The method of claim 50, wherein the curved surface is a cylindrical surface.

Claim 52. (Withdrawn) An article, comprising:
a cylindrical cladding having an axis;
a core surrounding the cladding comprising a liquid crystal;
wherein the liquid crystal is aligned substantially parallel to an alignment direction that is uniform through a cross-section of the cylindrical cladding.

Claim 53. (Withdrawn) A method, comprising:
overlapping at least three beams to form an interference pattern, wherein the beams originate from the same source;
exposing an alignment material to the interference pattern; and
exposing the alignment material to a liquid crystal,
wherein the liquid crystal aligns relative to the alignment material based on the interference pattern.